

Nd:YLF Lasers



S.P.Morato; N.D.Vieira Jr.; W.E.Rossi, G.E.C.Nogueira; S.L.Baldochi; I.M.Ranieri; M.B.de Camargo; L.Gomes; M. M.F.Vieira; D.G.Leme; J.R.Berreta and F.E.da Costa IPEN-CNEN/SP - Caixa Postal 11049 - Pinheiros - Brasil



#### ABSTRACT

Since the discovery of the laser, Nd:YAG crystals became one of the most used laser medium. As an alternative for the host material we have been developing lasers based on an alphabetic material, LiYF4, where the Nd is one of the possible dopents. Along with the crystal growing developments, we have been developing the associated laser technology, including rod preparation, pumping cavities, power supplies, cooling systems, resonator configurations and controlling of the temporal behavior of the laser regime. So far we have developed three prototypes in the pulsed regime and three in the c.w..

## LASER PROGRAM AT IPEN

Since the end of the sixties, a materials science program started at IPEN which included During the crystals and its defects. seventies, a major effort was carried out in the comprehension of the radiation induced defects in either pure or doped crystals. The main concern was with alkali halides and some solution grown crystals. Within this scope, the optical spectroscopic properties of these subject of fundamental materials were investigations, concomitantly with the advent of color centers as useful laser sources [1]. The combined effect of having the crystal growing facilities and the spectroscopic tools led to the first color center laser in our ·laboratories [2]. At that time we realized that Nd doped crystals would be an interesting field of either basic research and technology. Since then, the main efforts of the laser development group at IPEN has been towards the achievement of Nd:YLF lasers.

## LASER CRYSTALS [3,4]

The choice of the scheelite-structured LiYF<sub>4</sub> (YLF) matrix as the host material for Nd<sup>3+</sup> ions is due to several reasons:

1) The substitutional Nd ion is located at the Yttrium site, with the same valence. This site has no inversion symmetry (group  $S_4$ ), therefore the proper admixture of even parity terms in the f manifold wave function allows for the optical transition strength needed for the laser transitions. Due to the small crystal field strength the laser transition cross section is smaller in YLF than in YAG, but the radiative decay time is conversely longer allowing for a higher energy storage;

2) The YLF is an alphabetic material, concerning the introduction of rare earth ions in the Yttrium site, allowing for higher levels of dopant concentration (in some cases even 100% ) and rare earth simultaneous doping; 3) YLF has a melting point much lower than the YAG, therefore, the need for special furnaces and very special crucible materials is slightly less demanding. Nevertheless, platinum crucibles are still needed, but they reutilized after can be the material processing. One drawback of this crystal is the need of hydrofluoric acid atmosphere during the material processing;

4) The thermal conductivity is two times smaller in YLF than in YAG crystals but the index of refraction is less dependent on the crystal temperature. Therefore, the thermal lensing effect is less serious than in the Nd:YAG crystal. Besides, its natural birefringence overwhelms the thermally induced one, what makes it a better material for high power operation;

5) The laser transitions are twofold, one at 1.047 mm ( $\pi$  polarized) and another at 1.053 mm ( $\sigma$  polarized), and can be chosen by a proper alignment of the crystal axis with respect to the optical resonator axis. The latter transition matches perfectly with the emission line of the Nd:Glass phosphate amplificator in the inertial confinement fusion experiments; 6) The homogeneous broadening of the laser transition in YLF is greater than in YAG, therefore it supports much shorter pulses in the mode-locked regime.

## CRYSTAL GROWTH [5]

To prepare the Nd:YLF crystals, we first start from ultra pure oxide rare earth powders, Nd2O3 and Y2O3. These materials are then thermally treated in a dynamic hydrofluoric

in order to obtain the acid atmosphere respective NdF3 and YF3 composites. These with LiF fluorides are then mixed non-stoichiometrically and excess of NdF3 is added to achieve the desired final concentration. These materials are then synthesized to obtain the final compound. The next step is to zone refine the compound at the crystal melting point temperature, also under HF atmosphere . The zone refining region is of the order of two centimeters and this hot zone passes through the compound with a constant speed. Impurities and the excesses of YF3 are left at the end of the ingot. The final ingot is a transparent material, but it is not a single crystal. This procedure guarantees the purity and the stoichiometric composition of the final compound since it malta incongruently. The next step is the single crystal growth by the Czochraslki method under Argon atmosphere with a very slow growing rate. The whole process takes about two months. The crystal is then submitted to a strain relief thermal treatment that takes another few days.

# CRYSTAL CHARACTERIZATION

The crystal samples can be characterized in two stages of the preparation procedure: first, just after the zone refining procedure where the ingot composition is analyzed by spectrographyc methods with ppm resolution and second, the single crystal is analyzed also in terms of the Nd concentration of the single crystal as well 88 its spectroscopic characteristics, such as optical absorption, time, crystalographyc emission, decay orientation and the presence of domains. Figure 1 shows the energy level diagrams of Nd in the LiYF4 crystal. In our lasers, the is oriented with the c axis crvstal perpendicular to the rod axis to favor the  $\pi$ polarization, that shows the higher emission cross section. These measurements provide a first rough idea of the existence of structural stress that would lead to some light depolarization which is detrimental to laser action.

In the case of the Nd:YLF crystal its optical properties are well known, such that a comparison with the literature is enough to evaluate the quality of the crystal. Along with the Nd laser development, we are also developing Er:YLF crystals. In this case, the system is much more complex due to the possibility attaining high Erbium of concentrations and therefore there is the possibility of energy exchange between neighbor ions , that affect the total decay time, reducing the laser efficiency. Besides, due to the transitions of low energy and to the possibility of energy migration along the

ions, the presence of undesired impurities can lead to a quenching effect of the green luminescence 161. Table 1 shows the measurements of the luminescence branching ratios in the case of the Er:YLF. We are also characterizing this system either with conventional spectroscopy techniques and also with the photoacoustic methods which allow for the determination of the absolute luminescence quantum efficiency. Table 2 shows the typical results obtained for the Nd:YLF crystals .



Figure 1:  $Nd^{3+}$  energy levels in LiYF<sub>4</sub> crystal. The emissions at 1.047  $\mu m(\pi)$  and 1.053  $\mu m(\sigma)$  are shown.

Table 2: Luminescence quantum efficiency for the absorption bands centered at  $\lambda_{\pm}$  ( $\mu$ m) with emission at 1.047 and a 1.053  $\mu$ m.

λ (μm)	η (1.047 μ m)	η (1.054 μm)
0.517	0.12+0.02	0.18+0.02
0.577	0.16+0.02	0.20+0.02
0.742	0.17+0.02	0.13+0.02
0.792	0.29+0.02	0.27+0.02

Before going into the crystal rod preparation it is also possible to verify the laser action using a collinear pumping scheme where the crystal sample is very small, reducing the need for careful crystal preparation. This scheme was tested with the first Nd:YLF crystals grown in our lab, and with the laser operation parameters we were able to determine the amount of losses introduced by the crystal [7].

Table 1: Branching ratio of Er3+ in YLF crystal;  $\lambda$  is the most intense emission wavelength of the multiplet measured at 77 K,  $\eta_{\rm T}$  is the total luminescence efficiency, B<sub>1</sub> is branching ratio, and the  $\Delta\lambda$  is the multiplet width.

3+,	<sup>+</sup> ] λ(μm) (Δλ)		η		B	B <sub>1</sub> (%)	
[Er ]		Transition	77 K	300 K	77 K	300 K	
1%	0.55 (0.04)	${}^{4}S_{3/2} \longrightarrow {}^{4}I_{15/2}$	1	0.54	48.6	21.0	
	0.67 (0.03)`	${}^{4}F_{9/2} \longrightarrow {}^{4}I_{15/2}$			27.5	8.3	
	0.70 (0.03)	${}^{2}\mathrm{H}_{9/2} \longrightarrow {}^{4}\mathrm{I}_{11/2}$			4.1	1.3	
	0.85 (0.03)	${}^{4}S_{3/2} \longrightarrow {}^{4}I_{13/2}$			10.5	2.8	
	>1.10	mid-IR			9.3	66.6	
40%	0.55 (0.03)	${}^{4}S_{3/2} \longrightarrow {}^{4}I_{15/2} 0$	. 041	0.006	38.1	1.4	
	0.67 (0.03)	${}^{4}F_{9/2} \longrightarrow {}^{4}I_{15/2}$			13.7	1.6	
	0.70 (0.C3)	$^{2}\text{H}_{9/2} \longrightarrow {}^{4}\text{I}_{11/2}$			3.5	1.4	
	0.85 (0.03)	${}^{4}S_{3/2} \longrightarrow {}^{4}I_{13/2}$			6. )	0.2	
	>1.10	mid-IR			37.8	95.4	

average power, where there is no need for forced cooling, a simple closed coupled cavity consisting of a highly reflecting cylindrical tube is enough for achieving high efficiencies. For c.w. or high power pulsed lasers, where water cooling is necessary, the usual configuration is the elliptical one, with the rod at one of the foci and the pump

> laser at the other. We have used both configurations, coated with gold, silver or diffuse material.

# RESONATOR CONFIGURATIONS

For the pulsed mode operation, in order to extract the maximum output power in all possible oscillating modes, the typical mirror configuration is either with flat mirrors or convex-concave configuration, in order to fill the laser rod with the spatial mode. In this case, the rod acts as a dynamic focusing element limiting the useful laser area. In the case of the Nd:YLF this problem is minimized. For the c.w. mode the  $TEM_{00}$  mode is desired so the flat concave resonator is the used one.

#### POWER SUPPLIES AND COOLING SYSTEMS

The power supplies for pulsed mode operation were developed to cover the range of



Figure 2: Pulse of the Q-switched Nd:YLF laser using  $\text{LiF:F}_2$  crystals as the passive Q-switcher.

#### ROD PREPARATION.

Single crystals are grown typically with the boule oriented with the c axis perpendicular to the growing direction, with typical useful dimensions of 3 cm of diameter and 8.5 cm long. Rods are then extracted in order to maximize the useful area. Rod diameters can range from 4 mm to 6 mm and they have typically 75 mm of length. The ends are then polished in a special jig in order to obtain a surface flatness of 1/10, in the near infrared, with a parallelism of 30" of arc. They are anti reflection coated with a four layer design. The barrel finish is the usual grit 400 [8].

## PUMPING CAVITIES

The coupling of the pumping lamp with the laser rod is done by a reflecting enclosure, whose shape depends on the particular application. For pulsed lasers with a low 50 to 250 J and pulse durations can range from 100 ms to 310 ms. For the continuous wave, the electrical output power ranges from 1000 W up to 3000 W. The electrical system has safety interlocks to avoid overheating of the system and also to control the deionized water quality. A special triggering circuit is needed for the high pressure arc lamp in the c.w. operation. For high power lasers, the cooling is firstly done by a primary closed deionized water circuit and then by an external secondary water circuit.

# LASER PROTOTYPES

## a) Pulsed models

Due to the simplicity of construction, the first lasers developed were the pulsed ones, and 3 models were already constructed [8]. One is a hand held, rugged model, with a parallel flat mirror configuration, with a compact power supply, low repetition rate (0.3 Hz), that delivers 70 mJ in a 0.3 ms pulse duration in multimode operation. The pump lamp is a low pressure Xe flash lamp. The second pulsed laser developed uses the same pump lamp but the electrical power source can deliver up to 50 J. The resonator configuration is also flat and parallel with a diffuse pumping cavity. The multi mode free running energy is 500mJ.

Using a saturable absorber consisting of LiF:F2 crystal we were able to optimize the Q-switching operation [9] of this laser, obtaining pulses as short as 5 ns, what is comparable to that obtained using active Q-switchers. Figure 2 shows the pulse output obtained in this case. These centers are long lived at room temperature even under working peak powers of tens of megawatts. The mechanism of formation, its spectroscopic properties and stability were subject of investigation in our lab. It was found that the best LiF crystals are the ultra pure ones, that can be obtained in our growth facilities. By increasing the length of the resonator and decreasing the output coupling , mode locking regime with 100 % modulation was observed in this system. An estimate of the pulse duration with a background free second harmonic generation autocorrelator showed pulses with ,at most, 80 ps of duration. With this high peak powers we then used a home grown KDP to generate the second harmonic.

The third model is an industrial prototype made of a Nd:Glass rod, pumped by two lamps in a double ellipse configuration, with an electrical input power of 250 J in a plane concave configuration, using a long radius mirror.The output energy of this laser is 6 J, with a pulse duration of 100 ms, tailored to milling of stainless steel.

#### b) CW Lasers

For the c.w. operation mode, we have developed three laser models. The first laser is pumped by a tungsten halogen lamp in an elliptical pumping cavity, gold plated, cooled by forced air. The laser rod is cooled by water flow. The resonator configuration is plano concave, multimode, and the useful output power achieved was 400 mW. The second model is an upgrading of the preceding one, using two lamps for pumping. In this case, the maximum output power is 1 W. The third model uses a high pressure Kr arc lamp and in this case the rod and the flash lamp are water cooled in a flooded pumping cavity. In this case , the thermal lens can be easily compensated and therefore the resonator configuration is the standard plane concave. The maximum electrical input power is 3 KW and in this condition we obtained 15 W in multimode operation and 3 W in the TEM00, in a concave-convex resonator.

## REFERENCES

- [1] L.F. Mollenauer and D.H. Olson, Appl. Phys. Lett, 24, 386 (1974);
- [2] N.D.Vieira, Jr, I.M.Ranieri and S.P. Morato, Phys. Stat. Sol.(a) 73, K115 (1982);
- [3] W. Koechner, Solid State Laser Engineering", Springer Verlag. N.Y. 1976;
- [4] A.A. Kaminskii, "Laser Crystals"; Springer-Verlag, N.Y. (1981);
- [5] R. E. Thoma, C.F. Weaver, H.A. Friedman,
  H. Insley, L.A. Harris and H.L. Yakel, Jr,
  J. Phys. Chem. 65, 1096 (1961);
- [6] M.B. Camargo, L. Gomes and S.P. Morato, submitted to Phys. Rev. B (1990);
- [7] R. Amaral Neto, Desenvolvimento de um Laser de Estado Solido de Nd:YLF, M. Sc. Thesis (1984).
- [8] W. de Rossi, J.R. Berretta, N.D. Vieira Jr., G.E.C. Nogueira and S. P. Morato, Terceiro Encontro Latino Americano sobre Lasers e suas Aplicacmes, Mar del Plata, setembro de 1988.
- [9] W. de Rossi, N. D. Vieira Jr., F. E da Costa, S. L. Baldochi and S. P. Morato, "Optimization of a Color Center Q-switched Nd:YLF Laser", in Digest of Topical Meeting on Advanced Solid-State Lasers 1990 (Optical Society of America, Washington, D. C. 1990), p. 211 - 213.